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Silicon Carbide Schottky Diode

1200 V, 30 A

FFSH30120A-F155

Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

Features

- Max Junction Temperature 175°C
- Avalanche Rated 361 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
- This Device is Pb–Free, Halogen Free/BFR Free and RoHS Compliant

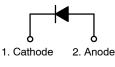
Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits



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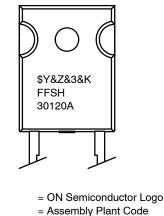


Schottky Diode



TO-247-2LD CASE 340DC

MARKING DIAGRAM



	0
&Z	= Assembly Plant Code
&3	= Numeric Date Code
&K	= Lot Code
FFSH30120A	= Specific Device Code

\$Y

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFSH30120A-F155

Symbol	Parameter	Value	Unit	
V _{RRM}	Peak Repetitive Reverse Voltage		1200	V
E _{AS}	Single Pulse Avalanche Energy (Note 1)		361	mJ
١ _F	Continuous Rectified Forward Current @ T _C <	s Rectified Forward Current @ T _C < 155°C		A
	Continuous Rectified Forward Current @ T_C <	46		
I _{F, Max}	Non-Repetitive Peak Forward Surge Current	T _C = 25°C, 10 μs	1500	А
		T _C = 150°C, 10 μs	1400	А
I _{F,SM}	Non-Repetitive Forward Surge Current	Half-Sine Pulse, t _p = 8.3 ms	230	А
I _{F,RM}	Repetitive Forward Surge Current	Half-Sine Pulse, t _p = 8.3 ms	80	А
Ptot	Power Dissipation	$T_{\rm C} = 25^{\circ}{\rm C}$	500	W
		T _C = 150°C	83	W
T _J , T _{STG}	Operating and Storage Temperature Range	–55 to +175	°C	
	TO247 Mounting Torque, M3 Screw	60	Ncm	

ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. E_{AS} of 361 mJ is based on starting $T_J = 25^{\circ}$ C, L = 0.5 mH, $I_{AS} = 38$ A, V = 50 V.

THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max	0.3	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25° C unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
V _F Forward Voltage	Forward Voltage	$I_{\rm F} = 30$ A, $T_{\rm C} = 25^{\circ}{\rm C}$	-	1.45	1.75	V
		I _F = 30 A, T _C = 125°C	-	1.7	2.0	
		I _F = 30 A, T _C = 175°C	-	2.0	2.4	1
I _R Reverse Currer	Reverse Current	$V_{\rm R}$ = 1200 V, $T_{\rm C}$ = 25°C	-	-	200	μΑ
		$V_{\rm R}$ = 1200 V, $T_{\rm C}$ = 125°C	-	-	300	
		$V_{\rm R}$ = 1200 V, $T_{\rm C}$ = 175°C	-	-	400	1
Q _C	Total Capacitive Charge	V = 800 V	-	175	-	nC
C Total Capacitance	C Total Capacitance	V _R = 1 V, f = 100 kHz	-	1740	-	pF
		V _R = 400 V, f = 100 kHz	-	159	-	
		V _R = 800 V, f = 100 kHz	-	130	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

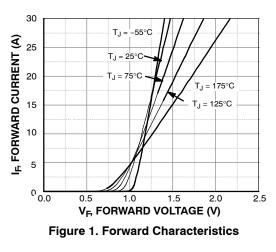
ORDERING INFORMATION

Part Number	Top Marking	Package	Shipping
FFSH30120A-F155	FFSH30120A	TO-247-2LD (Pb-Free)	30 Units / Tube

FFSH30120A-F155

TYPICAL CHARACTERISTICS

(T_J = 25°C unless otherwise noted)



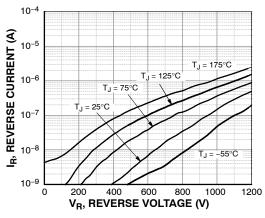


Figure 2. Reverse Characteristics

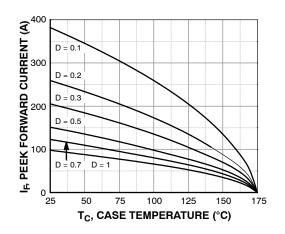


Figure 3. Current Derating

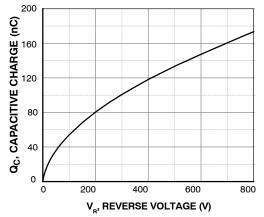


Figure 5. Capacitive Charge vs. Reverse Voltage

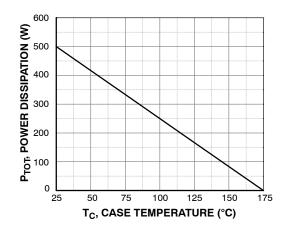


Figure 4. Power Derating

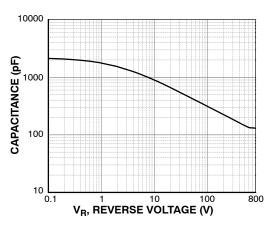


Figure 6. Capacitance vs. Reverse Voltage

FFSH30120A-F155

TYPICAL CHARACTERISTICS

(T_J = 25°C unless otherwise noted)

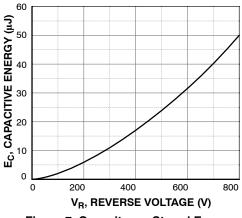


Figure 7. Capacitance Stored Energy

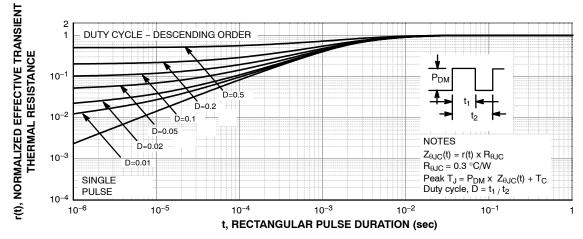


Figure 8. Junction-to-Case Transient Thermal Response Curve

TEST CIRCUIT AND WAVEFORMS

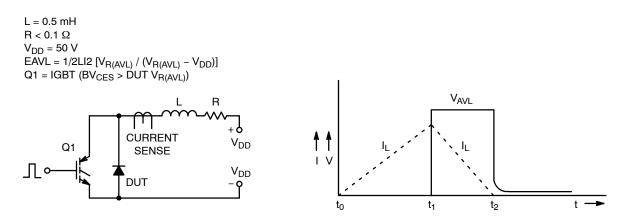
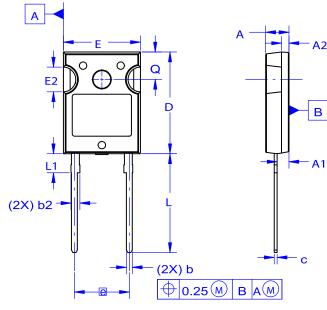
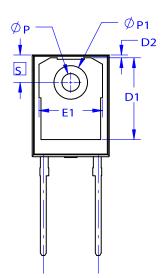


Figure 9. Unclamped Inductive Switching Test Circuit & Waveform

PACKAGE DIMENSIONS

TO-247-2LD CASE 340DC ISSUE O





NOTES:

- A. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
- **B. ALL DIMENSIONS ARE IN MILLIMETERS.**
- C. DIMENSION AND TOLERANCE AS PER ASME Y14.5-2009.
- D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
- E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.

DIM	MILLIMITERS			
DIM	MIN	NOM	MAX	
А	4.58	4.70	4.82	
A1	2.20	2.40	2.60	
A2	1.40	1.50	1.60	
b	1.17	1.26	1.35	
b2	1.60	1.72	1.84	
с	0.51	0.61	0.71	
D	20.32	20.57	20.82	
D1	13.08	~	~	
D2	0.51	0.93	1.35	
E	15.37	15.62	15.87	
E1	12.81	~	~	
E2	4.96	5.08	5.20	
е	~	11.12	~	
L	19.75	20.00	20.25	
L1	3.69	3.81	3.93	
ØР	3.51	3.58	3.65	
Ф Р1	6.60	6.80	7.00	
Q	5.34	5.46	5.58	
S	5.34	5.46	5.58	

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PUBLICATION ORDERING INFORMATION

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